

Si5391 Data Sheet

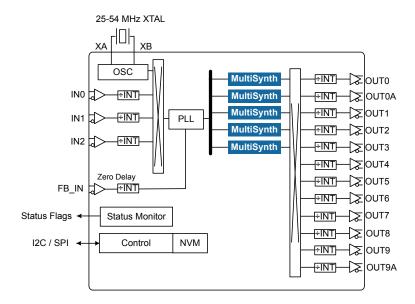
Ultra Low-Jitter, 12-Output, Any-Frequency, Any-Output Clock Generator

The any-frequency, any-output Si5391 clock generators combine a wide-band PLL with proprietary MultiSynth[™] fractional synthesizer technology to offer a versatile and high performance clock generator platform. This highly flexible architecture is capable of synthesizing a wide range of integer and non-integer related frequencies up to 1 GHz on 12 differential clock outputs while delivering sub-100 fs rms phase jitter performance optimized for 100G/200G/400G applications. Each of the clock outputs can be assigned its own format and output voltage enabling the Si5391 to replace multiple clock ICs and oscillators with a single device making it a true "clock tree on a chip."

The Si5391 can be quickly and easily configured using ClockBuilderPro software. Custom part numbers are automatically assigned using ClockBuilder Pro[™] for fast, free, and easy factory pre-programming or the Si5391 can be programmed via I2C and SPI serial interfaces.

Applications:

- 100/200/400G switches
- 56G/112G PAM4 SerDes reference clocks
- · Clock tree generation replacing XOs, buffers, signal format translators
- · Clocking for FPGAs, processors, memory
- · Ethernet switches/routers
- OTN framers/mappers/processors



KEY FEATURES

- Generates any combination of output frequencies from any input frequency
- Ultra-low jitter performance
 - 69fs RMS (Precision Calibration)
 - · 75fs RMS (integer mode)
 - 115fs RMS (fractional mode)
- Input frequency range:
 - External crystal: 25 to 54 MHz
 - Differential clock: 10 to 750 MHz
 - · LVCMOS clock: 10 to 250 MHz
- Output frequency range:
 - Differential: 100 Hz to 1028 MHz
- LVCMOS: 100 Hz to 250 MHz
- Highly configurable outputs compatible with LVDS, LVPECL, LVCMOS, CML, and HCSL with programmable signal amplitude
- Si5391: 4 input, 12 output, 64-QFN 9x9mm

1. Features List

The Si5391 features are listed below:

- Generates any combination of output frequencies from any input frequency
- Ultra-low phase jitter performance
 - 69fs RMS (Precision Calibration)
 - 75fs RMS (integer mode)
 - 115fs RMS (fractional mode)
- Input frequency range:
 - External crystal: 25 to 54 MHz
 - Differential clock: 10 to 750 MHz
 - LVCMOS clock: 10 to 250 MHz
- Output frequency range:
 - Differential: 100 Hz to 1028 MHz
 - LVCMOS: 100 Hz to 250 MHz
- Highly configurable outputs compatible with LVDS, LVPECL, LVCMOS, CML, and HCSL with programmable signal amplitude
- Optional zero delay mode
- Glitchless on the fly output frequency changes

- DCO mode: as low as 0.001 ppb steps
- Core voltage
 - VDD: 1.8 V ±5%
 - VDDA: 3.3 V ±5%
- Independent output clock supply pins
 - 3.3 V, 2.5 V, or 1.8 V
- Serial interface: I2C or SPI
- In-circuit programmable with non-volatile OTP memory
- ClockBuilder Pro software simplifies device configuration
- 64-QFN 9x9mm
- Temperature range: –40 to +85 °C
- Pb-free, RoHS-6 compliant

2. Related Documents

Document/Resource	Description/URL
Si5391 Family Reference Manual	https://www.silabs.com/documents/public/reference-manuals/si5391-reference-man- ual.pdf
Crystal Reference Manual	https://www.silabs.com/documents/public/reference-manuals/si534x-8x-recommended- crystals-rm.pdf
Si5391A-A-EVB User Guide	https://www.silabs.com/documents/public/user-guides/ug334-si5391-evb.pdf
Si5391P-A-EVB User Guide	https://www.silabs.com/documents/public/user-guides/ug334-si5391-evb.pdf
Quality and Reliability	http://www.silabs.com/quality
Development Kits	https://www.silabs.com/products/development-tools/timing/clock#highperformance
ClockBuilder Pro (CBPro) Software	https://www.silabs.com/products/development-tools/software/clockbuilder-pro-software

3. Ordering Guide

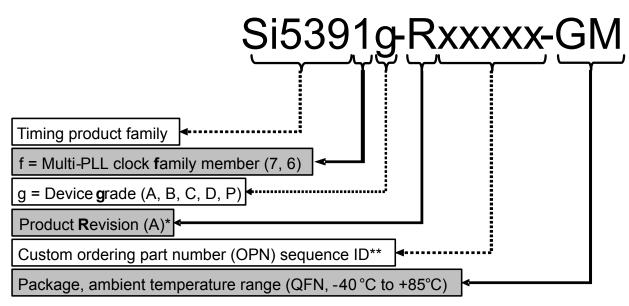
Ordering Part Num- ber (OPN)	Number of Input/ Output Clocks	Output clock fre- quency range (MHz)	Frequency Synthe- sis Mode	Package	Temperature Range
Si5391A-A-GM ^{1, 2}	4/12	0.001 to 1028	Integer and Fraction-	64-QFN 9x9mm	-40 to 85C
Si5391B-A-GM ^{1, 2}		0.001 to 350	al		
Si5391C-A-GM ^{1, 2}		0.001 to 1028	Integer Only		
Si5391D-A-GM ^{1, 2}		0.001 to 350			
Si5391P-A-EGM	Crystal / 12	312.5/156.25/100/50 /25	Precision Calibration		
Si5391A-A-EVB	4 / 12	Any-Frequency, Any Output	Integer and Fraction- al	Evaluation Board (A/B/C/D Grades)	
Si5391P-A-EVB	Crystal /12	Ultra low jitter clocks for 56G/112G SerDes	Precision Calibration	Evaluation Board (P Grade)	

Table 3.1. Si5391 Ordering Guide

Note:

1. Add an R at the end of the OPN to denote tape and reel ordering options.

2. Custom, factory pre-programmed devices are available. Ordering part numbers are assigned by Silicon Labs and the ClockBuilder Pro software utility. Custom part number format is: e.g., Si5391A-Axxxx-GM, where "xxxxx" is a unique numerical sequence representing the preprogrammed configuration.



*See Ordering Guide table for current product revision ** 5 digits; assigned by ClockBuilder Pro



Table of Contents

1.	Features List	. 2
2.	Related Documents	. 3
3.	Ordering Guide	. 4
4.	Functional Description.	. 7
	4.1 Power-up and Initialization	. 7
	4.2 Frequency Configuration	. 7
	4.3 Inputs	. 7
	4.3.1 XA/XB Clock and Crystal Input	
	4.3.2 Input Clocks (IN0, IN1, IN2)	
	4.4 Fault Monitoring	
	4.4.1 Status Indicators	
	4.4.2 Interrupt Pin (INTRb)	.10
	4.5 Outputs	
	4.5.1 Grade A/B/C/D	
	4.5.3 Output Signal Format	
	4.5.4 Differential Output Terminations.	
	4.5.5 Programmable Common Mode Voltage for Differential Outputs	
	4.5.7 LVCMOS Output Impedance and Drive Strength Selection.	
	4.5.8 LVCMOS Output Signal Swing	
	4.5.9 LVCMOS Output Polarity	
	4.5.10 Output Enable/Disable .	
	4.5.12 Synchronous/Asynchronous Output Disable Feature	
	4.5.13 Zero Delay Mode (Grade A/B/C/D)	
	4.5.14 Output Crosspoint	
	4.6 Power Management.	
	4.7 In-Circuit Programming.	
	4.8 Serial Interface	
	4.9 Custom Factory Preprogrammed Devices	
	4.10 Enabling Features and/or Configuration Settings Not Available in ClockBuilder Pro for Factory	
	Programmed Devices	
5.	Register Map	. 17
	5.1 Addressing Scheme	.17
6.	Electrical Specifications	. 18
7.	Detailed Block Diagrams	32

8.	Typical Operating Characteristics	3
9.	Pin Descriptions	4
10.	Package Outlines	9
	10.1 Si5391 9x9 mm 64-QFN Package Diagram	9
11.	PCB Land Pattern	0
12.	Top Marking	2
13.	Device Errata	3
14.	Revision History.	4

4. Functional Description

The Si5391 combines a wide band PLL with next generation MultiSynth technology to offer the industry's most versatile and high performance clock generator. The PLL locks to either an external **crystal** between XA/XB or to an external **clock** connected to XA/XB or IN0, 1, 2. A fractional or integer multiplier takes the selected input clock or cystal frequency up to a very high frequency that is then divided by the MultiSynth output stage to any frequency in the range of 100 Hz to 1 GHz on each output. The MultiSynth stage can divide by both integer and fractional values. The high-resolution fractional MultiSynth dividers enable true any-frequency input to anyfrequency on any of the outputs. The output drivers offer flexible output formats which are independently configurable on each of the outputs. This clock generator is fully configurable via its serial interface (I²C/SPI) and includes in-circuit programmable non-volatile memory.

4.1 Power-up and Initialization

Once power is applied, the device begins an initialization period where it downloads default register values and configuration data from NVM and performs other initialization tasks. Communicating with the device through the serial interface is possible once this initialization period is complete. No clocks will be generated until the initialization is done. There are two types of resets available. A hard reset is functionally similar to a device power-up. All registers will be restored to the values stored in NVM, and all circuits will be restored to their initial state including the serial interface. A hard reset is initiated using the RSTb pin or by asserting the hard reset bit. A soft reset bypasses the NVM download. It is simply used to initiate register configuration changes.

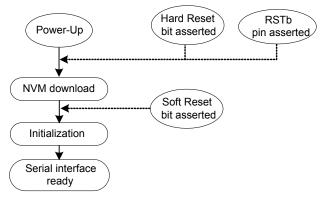


Figure 4.1. Si5391 Power-Up and Initialization

4.2 Frequency Configuration

The phase-locked loop is fully contained and does not require external loop filter components to operate. Its function is to phase lock to the selected input and provide a common reference to the MultiSynth high-performance fractional dividers.

A crosspoint mux connects any of the MultiSynth divided frequencies to any of the outputs drivers. Additional output integer dividers provide further frequency division by an even integer from 2 to (2^25)-2. The frequency configuration of the device is programmed by setting the input dividers (P), the PLL feedback fractional divider (Mn/Md), the MultiSynth fractional dividers (Nn/Nd), and the output integer dividers (R). Silicon Labs's ClockBuilder Pro configuration utility determines the optimum divider values for any desired input and output frequency plan.

4.3 Inputs

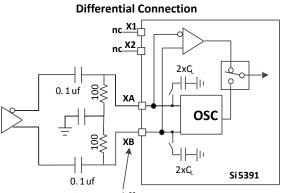
The Si5391 requires either an external crystal at its XA/XB pins or an external clock at XA/XB or IN0, 1, 2.

4.3.1 XA/XB Clock and Crystal Input

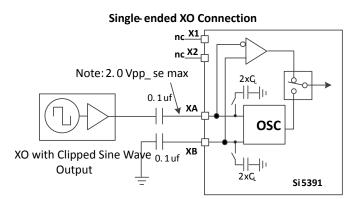
An internal crystal oscillator exists between pin XA and XB. When this oscillator is enabled, an external crystal connected across these pins will oscillate and provide a clock input to the PLL. A crystal frequency of 25 MHz can be used although crystals in the frequency range of 48 MHz to 54 MHz are recommended for best jitter performance. The Si5391 Family Reference Manual provides additional information on PCB layout recommendations for the crystal to ensure optimum jitter performance. Refer to Table 6.12 Crystal Specifications on page 30 for crystal specifications. Si5391P must use a 48 MHz crystal input.

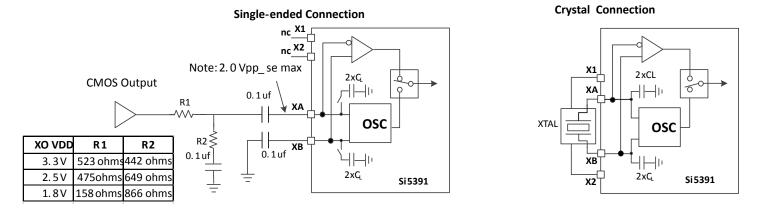
To achieve optimal jitter performance and minimize BOM cost, a crystal is recommended on the XA/XB reference input. A clock (e.g., XO) may be used in lieu of the crystal, but it will result in higher output jitter. See the Si5391 Family Reference Manual for more information.

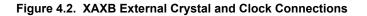
Selection between the external XTAL or input clock is controlled by register configuration. The internal crystal load capacitors (C_L) are disabled in the input clock mode. Refer to Table 6.3 Input Clock Specifications on page 20 for the input clock requirements at XAXB. Both a single-ended or a differential input clock can be connected to the XA/XB pins as shown in the figure below. A P_{XAXB} divider is available to accommodate external clock frequencies higher than 54 MHz.



Note: 2.5 Vpp diff max

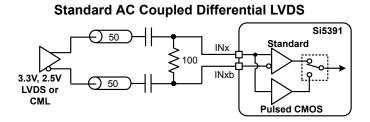




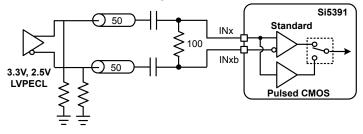


4.3.2 Input Clocks (IN0, IN1, IN2)

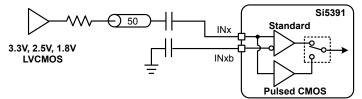
A differential or single-ended clock can be applied at IN2, IN1, or IN0. The recommended input termination schemes are shown in the figure below. Input clock support is not available on Precision Calibration Si5391P.



Standard AC Coupled Differential LVPECL



Standard AC Coupled Single Ended



Pulsed CMOS DC Coupled Single Ended

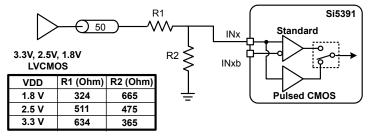


Figure 4.3. Termination of Differential and LVCMOS Input Signals

4.3.3 Input Selection (IN0, IN1, IN2, XA/XB)

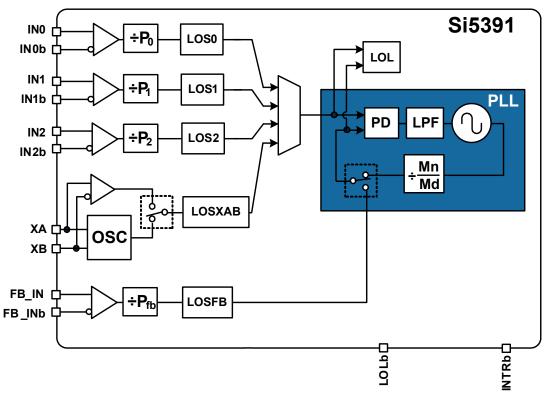
The active clock input is selected using the IN_SEL[1:0] pins or by register control. A register bit determines input selection as pin or register selectable. There are internal pull ups on the IN_SEL pins.

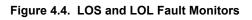
Table 4.1.	. Manual Input Selection Using IN_SEL[1:0] Pins
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IN_SE	:L[1:0]	Selected Input
0	0	INO
0	1	IN1
1	0	IN2
1	1	XA/XB

4.4 Fault Monitoring

The Si5391 provides fault indicators which monitor loss of signal (LOS) of the inputs (IN0, IN1, IN2, XA/XB, FB_IN) and loss of lock (LOL) for the PLL as shown in the figure below.





4.4.1 Status Indicators

The state of the status monitors are accessible by reading registers through the serial interface or with a dedicated pin (LOLb). Each of the status indicator register bits has a corresponding sticky bit in a separate register location. Once a status bit is asserted its corresponding sticky bit (_FLG) will remain asserted until cleared. Writing a logic zero to a sticky register bit clears its state.

4.4.2 Interrupt Pin (INTRb)

An interrupt pin (INTRb) indicates a change in state with any of the status registers. All status registers are maskable to prevent assertion of the interrupt pin. The state of the INTRb pin is reset by clearing the status registers.

4.5 Outputs

The Si5391 supports 12 differential output drivers which can be independently configured as differential or LVCMOS.

Each driver has a configurable voltage swing and common mode voltage covering a wide variety of differential signal formats. In addition to supporting differential signals, any of the outputs can be configured as single-ended LVCMOS (3.3 V, 2.5 V, or 1.8 V) providing up to 24 single-ended outputs, or any combination of differential and single-ended outputs.

4.5.1 Grade A/B/C/D

The Si539x grades A/B/C/D can generate any output frequency in any format with best-in-class jitter. These devices are available as a preprogrammed option or can be written to the device via I²C. The input/output frequency plan determines whether the output divider operates in integer or fractional mode. In the fractional mode, the device can generate any output frequency or any format from any input frequency with best-in-class jitter. Some frequency plans allow the user to use an integer mode that delivers even lower jitter. See the family reference manual for more details.

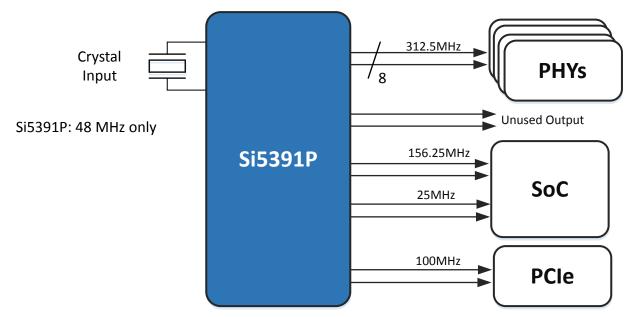
4.5.2 Grade P

Some applications, including 56G/112G PAM4 SerDes, require even better RMS phase jitter performance. The Si5391P grade internally calibrates out linearity errors to deliver the world's best jitter performance for applications focused on 312.5 MHz and 156.25 MHz frequencies. In addition to the primary 312.5/156.25MHz frequencies, the device can also support 100MHz, 50 MHz and 25 MHz outputs. The three conditions required for optimum performance Precision Calibration grade are:

1. An unused channel between the low-jitter 156.25/312.5MHz clocks and secondary clocks (100/50/25 MHz)

- 2. CMOS clocks should not be used for the secondary clocks.
- 3.48MHz crystal input. Clock input is not supported on Precision Calibration grade.

A typical example is shown in the figure below. With this configuration, it is possible to deliver a best-in-class 69 fs of phase jitter on the 312.5 MHz and 156.25 MHz outputs.





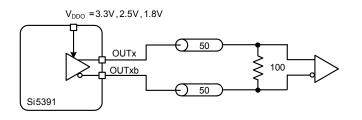
4.5.3 Output Signal Format

The differential output amplitude and common mode voltage are both fully programmable and compatible with a wide variety of signal formats including LVDS and LVPECL. In addition to supporting differential signals, any of the outputs can be configured as LVCMOS (3.3 V, 2.5 V, or 1.8 V) drivers providing up to 24 single-ended outputs, or any combination of differential and single-ended outputs.

4.5.4 Differential Output Terminations

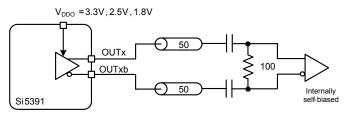
The differential output drivers support both ac-coupled and dc-coupled terminations as shown in the figure below.

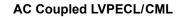
DC Coupled LVDS

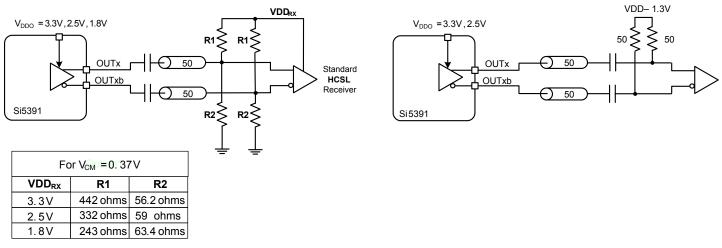


AC Coupled HCSL











4.5.5 Programmable Common Mode Voltage for Differential Outputs

The common mode voltage (VCM) for the differential modes are programmable so that LVDS specifications can be met and for the best signal integrity with different supply voltages. When dc coupling the output driver it is essential that the receiver should have a relatively high common mode impedance so that the common mode current from the output driver is very small.

4.5.6 LVCMOS Output Terminations

LVCMOS outputs are typically dc-coupled, as shown in the figure below.

DC Coupled LVCMOS

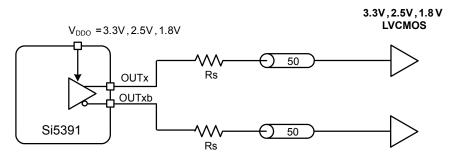


Figure 4.7. LVCMOS Output Terminations

4.5.7 LVCMOS Output Impedance and Drive Strength Selection

Each LVCMOS driver has a configurable output impedance. It is highly recommended that the minimum output impedance (strongest drive setting) is selected and a suitable series resistor (Rs) is chosen to match the trace impedance.

Table 4.2. Nominal Output Impedance vs. OUTx_CMOS_DRV (register)

VDDO		CMOS_DRIVE_Selection						
	OUTx_CMOS_DRV=1	OUTx_CMOS_DRV=2	OUTx_CMOS_DRV=3					
3.3 V	38 Ω	30 Ω	22 Ω					
2.5 V	43 Ω	35 Ω	24 Ω					
1.8 V	_	46 Ω	31 Ω					

4.5.8 LVCMOS Output Signal Swing

The signal swing (V_{OL}/V_{OH}) of the LVCMOS output drivers is set by the voltage on the VDDO pins. Each output driver has its own VDDO pin allowing a unique output voltage swing for each of the LVCMOS drivers.

4.5.9 LVCMOS Output Polarity

When a driver is configured as an LVCMOS output it generates a clock signal on both pins (OUTx and OUTxb). By default the clock on the OUTxb pin is generated with complementary polarity with the clock on the OUTx pin. The LVCMOS OUTx and OUTxb outputs can also be generated in phase.

4.5.10 Output Enable/Disable

The OEb pin provides a convenient method of disabling or enabling the output drivers. When the OEb pin is held high all outputs will be disabled. When held low, the outputs will be enabled. Outputs in the enabled state can be individually disabled through register control.

4.5.11 Output Driver State When Disabled

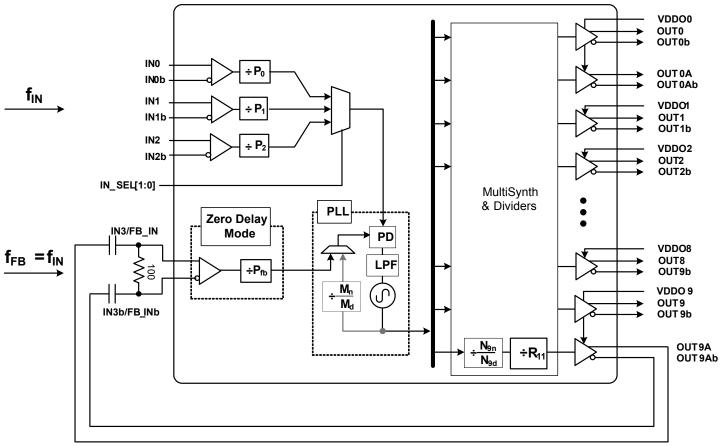
The disabled state of an output driver is configurable as: disable low or disable high.

4.5.12 Synchronous/Asynchronous Output Disable Feature

Outputs can be configured to disable synchronously or asynchronously. The default state is synchronous output disable. In synchronous disable mode the output will wait until a clock period has completed before the driver is disabled. This prevents unwanted runt pulses from occurring when disabling an output. In asynchronous disable mode the output clock will disable immediately without waiting for the period to complete.

4.5.13 Zero Delay Mode (Grade A/B/C/D)

A zero delay mode is available for applications that require fixed and consistent minimum delay between the selected input and outputs. The zero delay mode is configured by opening the internal feedback loop through software configuration and closing the loop externally as shown in the figure below. This helps to cancel out the internal delay introduced by the dividers, the crosspoint, the input, and the output drivers. Any one of the outputs can be fed back to the FB_IN pins, although using the output driver that achieves the shortest trace length will help to minimize the input-to-output delay. It is recommended to connect OUT9A to FB_IN for external feedback. The FB_IN input pins must be terminated and ac-coupled when zero delay mode is used. A differential external feedback path connection is necessary for best performance.



External Feedback Path

Figure 4.8. Si5391 Zero Delay Mode Setup

4.5.14 Output Crosspoint

The output crosspoint allows any of the N dividers to connect to any of the clock outputs.

4.5.15 Digitally Controlled Oscillator (DCO) Modes

Each MultiSynth can be digitally controlled so that all outputs connected to the MultiSynth change frequency in real time without any transition glitches. There are two ways to control the MultiSynth to accomplish this task:

- Use the Frequency Increment/Decrement Pins or register bits.
- Write directly to the numerator of the MultiSynth divider.

An output that is controlled as a DCO is useful for simple tasks such as frequency margining or CPU speed control. The output can also be used for more sophisticated tasks such as FIFO management by adjusting the frequency of the read or write clock to the FIFO or using the output as a variable Local Oscillator in a radio application.

4.5.15.1 DCO with Frequency Increment/Decrement Pins/Bits

Each of the MultiSynth fractional dividers can be independently stepped up or down in predefined steps with a resolution as low as 0.001 ppb. Setting of the step size and control of the frequency increment or decrement is accomplished by setting the step size with the 44 bit Frequency Step Word (FSTEPW). When the FINC or FDEC pin or register bit is asserted the output frequency will increment or decrement respectively by the amount specified in the FSTEPW.

4.5.15.2 DCO with Direct Register Writes

When a MultiSynth numerator and its corresponding update bit is written, the new numerator value will take effect and the output frequency will change without any glitches. The MultiSynth numerator and denominator terms can be left and right shifted so that the least significant bit of the numerator word represents the exact step resolution that is needed for your application.

4.6 Power Management

Several unused functions can be powered down to minimize power consumption. Consult the Si5391 Family Reference Manual and ClockBuilder Pro configuration utility for details.

4.7 In-Circuit Programming

The Si5391 is fully configurable using the serial interface (I²C or SPI). At power-up the device downloads its default register values from internal non-volatile memory (NVM). Application specific default configurations can be written into NVM allowing the device to generate specific clock frequencies at power-up. Writing default values to NVM is in-circuit programmable with normal operating power supply voltages applied to its V_{DD} and V_{DDA} pins. The NVM is two time writable. Once a new configuration has been written to NVM, the old configuration is no longer accessible. Refer to the Si5391 Family Reference Manual for a detailed procedure for writing registers to NVM.

4.8 Serial Interface

Configuration and operation of the Si5391 is controlled by reading and writing registers using the I²C or SPI interface. The I2C_SEL pin selects I²C or SPI operation. Communication with both 3.3 V and 1.8 V host is supported. The SPI mode operates in either 4-wire or 3-wire. See the Si5391 Family Reference Manual for details.

4.9 Custom Factory Preprogrammed Devices

For applications where a serial interface is not available for programming the device, custom pre-programmed parts can be ordered with a specific configuration written into NVM. A factory pre-programmed device will generate clocks at power-up. Use the ClockBuilder Pro custom part number wizard (www.silabs.com/clockbuilderpro) to quickly and easily request and generate a custom part number for your configuration. In less than three minutes, you will be able to generate a custom part number with a detailed data sheet addendum matching your design's configuration. Once you receive the confirmation email with the data sheet addendum, simply place an order with your local Silicon Labs sales representative. Samples of your pre-programmed device will ship to you typically within two weeks.

4.10 Enabling Features and/or Configuration Settings Not Available in ClockBuilder Pro for Factory Pre-Programmed Devices

As with essentially all software utilities, ClockBuilder Pro is continuously updated and enhanced. By registering at http://www.silabs.com and opting in for updates to software, you will be notified whenever changes are made and what the impact of those changes are. This update process will ultimately enable ClockBuilder Pro users to access all features and register setting values documented in this data sheet and the Si5391 Family Reference Manual. However, if you must enable or access a feature or register setting value so that the device starts up with this feature or a register setting, but the feature or register setting is NOT yet available in CBPro, you must contact a Silicon Labs applications engineer for assistance. An example of this type of feature or custom setting is the customizable amplitudes for the clock outputs. After careful review of your project file and custom requirements, a Silicon Labs applications engineer will email back your CBPro project file with your specific features and register settings enabled, using what is referred to as the manual "settings override" feature of CBPro. "Override" settings to match your request(s) will be listed in your design report file. Examples of setting "overrides" in a CBPro design report are shown below:

Table 4.3. Setting Overrides

Location	Name	Туре	Target	Dec Value	Hex Value
0128[6:4]	OUT6_AMPL	User	OPN & EVB	5	5

Once you receive the updated design file, simply open it in CBPro. After you create a custom OPN, the device will begin operation after startup with the values in the NVM file, including the Silicon Labs-supplied override settings.

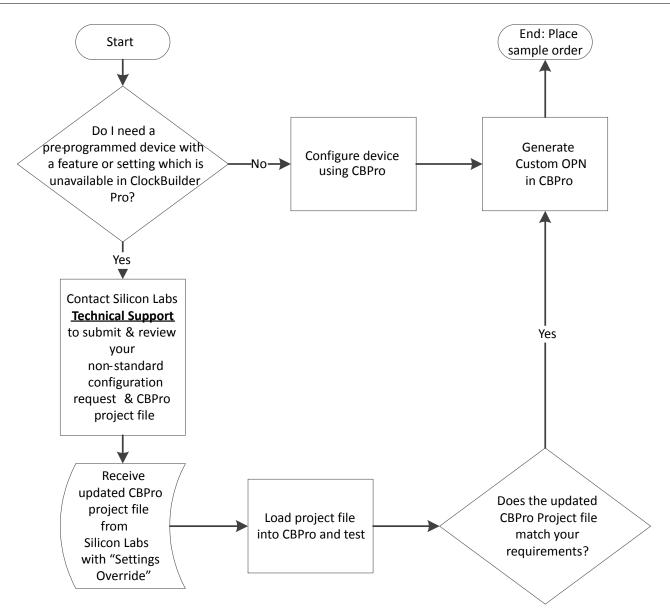


Figure 4.9. Flowchart to Order Custom Parts with Features not Available in CBPro

Note: Contact Silicon Labs Technical Support at www.silabs.com/support/Pages/default.aspx.

5. Register Map

The register map is divided into multiple pages where each page has 256 addressable registers. Page 0 contains frequently accessible registers such as alarm status, resets, device identification, etc. Other pages contain registers that need less frequent access such as frequency configuration, and general device settings. Refer to the Si5391 Family Reference Manual for a complete list of register descriptions and settings.

Note: It is strongly recommended that ClockBuilder Pro be used to create and manage register settings.

5.1 Addressing Scheme

The device registers are accessible using a 16-bit address which consists of an 8-bit page address + 8-bit register address. By default the page address is set to 0x00. Changing to another page is accomplished by writing to the 'Set Page Address' byte located at address 0x01 of each page.

6. Electrical Specifications

Table 6.1. Recommended Operating Conditions¹

 $(V_{DD}=1.8 V \pm 5\%, V_{DDA}=3.3 V \pm 5\%, T_{A}=-40 \text{ to } 85^{\circ}\text{C})$

Parameter	Symbol	Min	Тур	Мах	Units
Ambient Temperature	T _A	-40	25	85	°C
Junction Temperature	TJ _{MAX}	—	_	125	°C
Core Supply Voltage	V _{DD}	1.71	1.80	1.89	V
	V _{DDA}	3.14	3.30	3.47	V
Output Driver Supply Voltage	V _{DDO}	3.14	3.30	3.47	V
		2.37	2.50	2.62	V
		1.71	1.80	1.89	V

Note:

1. All minimum and maximum specifications are guaranteed and apply across the recommended operating conditions. Typical values apply at nominal supply voltages and an operating temperature of 25 °C unless otherwise noted.

Table 6.2. DC Characteristics

$(V_{DD}=1.8V \pm 5\%, V_{DDA}=3.3V \pm 5\%, V_{DDO}=1.8V \pm 5\%, 2.5V \pm 5\%, or 3.3V \pm 5\%, T_{A}= -40 \text{ to } 85^{\circ}\text{C})$

Parameter	Symbol	Test Condition	Min	Тур	Max	Units
Core Supply Current ¹	I _{DD}	Si5391	_	115	230	mA
	I _{DDA}	Si5391	_	120	130	mA
Output Buffer Supply Current	I _{DDOx}	LVPECL Output ²	_	22	26	mA
		@ 156.25 MHz				
		LVDS Output ²	_	15	18	mA
		@ 156.25 MHz				
		3.3 V LVCMOS ³ output		22	30	mA
		@ 156.25 MHz				
		2.5 V LVCMOS ³ output	_	18	23	mA
		@ 156.25 MHz				
		1.8 V LVCMOS ³ output	_	12	16	mA
		@ 156.25 MHz				
Total Power Dissipation ^{1, 4}	Pd	Si5391		880	1350	mW

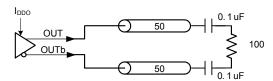
Note:

1. Si5391 test configuration: 7 x 2.5 V LVDS outputs enabled @ 156.25 MHz. Excludes power in termination resistors.

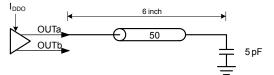
2. Differential outputs terminated into an ac-coupled 100 Ω load.

3. LVCMOS outputs measured into a 6-inch 50 Ω PCB trace with 5 pF load. The LVCMOS outputs were set to OUTx_CMOS_DRV=3, which is the strongest driver setting. Refer to the Si5391 Family Reference Manual for more details on register settings.





LVCMOS Output Test Configuration



4. Detailed power consumption for any configuration can be estimated using ClockBuilderPro when an evaluation board (EVB) is not available. All EVBs support detailed current measurements for any configuration.

Table 6.3. Input Clock Specifications

(V_DD =1.8 V \pm 5%, V_DDA = 3.3 V \pm 5%, T_A= –40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Тур	Max	Units
Standard Input Buffer with Diffe	erential or Sing	gle-Ended - AC-Coupled (IN0/	/IN0b, IN1/IN	11b, IN2/IN2b,	FB_IN/FB_IN	b)
Input Frequency Range	f _{IN}	Differential	10	_	750	MHz
		All Single-ended Signals	10	_	250	MHz
		(including LVCMOS)				
Input Voltage Swing ¹	V _{IN}	Differential AC-coupled	100	_	1800	mVpp_se
		f _{IN} < 250 MHz				
		Differential AC-coupled	225	_	1800	mVpp_se
		250 MHz < f _{IN} < 750 MHz				
		Single-ended AC-coupled	100	_	3600	mVpp_se
		f _{IN} < 250 MHz				
Slew Rate ^{2, 3}	SR		400	-	_	V/µs
Input Capacitance	C _{IN}		_	0.3	_	pF
Input Resistance Differential	R _{IN_DIFF}		_	16	_	kΩ
Input Resistance Single-Ended	R _{IN_SE}		_	8	_	kΩ
Pulsed CMOS Input Buffer - DC	Coupled (IN0,	, IN1, IN2) ⁴			1	
Input Frequency	f _{IN}		10	_	250	MHz
Input Voltage	V _{IL}		-0.2	_	0.4	V
	V _{IH}		0.8	_	_	V
Slew Rate ^{2, 3}	SR		400	_	_	V/µs
Minimum Pulse Width	PW	Pulse Input	1.6		_	ns
Input Resistance	R _{IN}		_	8	_	kΩ
REFCLK (Applied to XA/XB) ⁵						
Input Frequency Range	f _{IN}	Full operating range. Jitter performance may be re- duced.	10	_	200	MHz
		Range for best jitter.	48	_	54	MHz
Input Single-ended Voltage Swing	V _{IN_SE}		365	_	2000	mVpp_se
Input Differential Voltage Swing	V _{IN_DIFF}		365	—	2500	mVpp_diff
Slew Rate ^{2, 3}	SR	Imposed for best jitter per- formance	400	_	-	V/µs
Input Duty Cycle	DC		40	_	60	%

Parameter	Symbol	Test Condition	Min	Тур	Мах	Units
Note:						
1. Voltage swing is specified as 2. Imposed for jitter performance	•	Vcm + Vpr Vpp. Vcm + Vpr			 Vpp_diff = 2 [*]	*Vpp_se
 Pulsed CMOS mode is inten- they have a duty cycle signifi the input thresholds (V_{IL}, V_{IH} DC-coupled Pulsed LVCMOS Standard AC-Coupled, Single 	ded primarily for icantly less than s) of this buffer ar S in the Si5391 F	50%. A typical application ex e non-standard (0.4 and 0.8 amily Reference Manual. Ot	ample is a low V, respectively	<pre>/ frequency vid y), refer to the</pre>	leo frame sync input attenuate	pulse. Sinc
 4. DC-coupled CMOS Input But to IN0,1,2 it is required to ac- 5. Clock input is not supported 	-couple into the d	lifferential input buffer.	Pro for new d	esigns. For sir	ngle-ended LV	CMOS input

Table 6.4. Control Input Pin Specifications

(V_{DD} =1.8 V ± 5%, V_{DDA} = 3.3 V ± 5%, V_{DDS} = 3.3 V ± 5%, 1.8 V ± 5%, T_A = -40 to 85 °C)

Parameter	Symbol	Test Condition	Min	Тур	Max	Units		
Si5391 Control Input Pins (I2C_SEL, IN_SEL[1:0], RSTb, OEb, SYNCb, A1, SCLK, A0/CSb, FINC, FDEC, SDA/SDIO)								
Input Voltage	V _{IL}		—	_	0.3xV _{DDIO} ¹	V		
	V _{IH}		0.7xV _{DDIO} 1	_	_	V		
Input Capacitance	C _{IN}		—	2	_	pF		
Input Resistance	R _{IN}		_	20	_	kΩ		
Minimum Pulse Width	T _{PW}	RSTb, SYNCb, FINC, and FDEC	100	—	—	ns		
Frequency Update Rate	F _{UR}	FINC and FDEC	_	_	1	MHz		

Note:

1. V_{DDIO} is determined by the IO_VDD_SEL bit. It is selectable as V_{DDA} or V_{DD}. Refer to the Si5391 Family Reference Manual for more details on register settings.

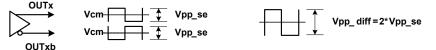
Table 6.5. Differential Clock Output Specifications

$(V_{DD}=1.8 V \pm 5\%, V_{DDA}=3.3 V \pm 5\%, V_{DDO}=1.8 V \pm 5\%, 2.5 V \pm 5\%, or 3.3 V \pm 5\%, T_{A}=-40 \text{ to } 85 \text{ °C})$

Parameter	Symbol	Test Con	dition	Min	Тур	Max	Units
Output Frequency	fout	MultiSynth	not used	0.0001	_	720	MHz
			-	733.33	_	800.00	
			-	825		1028	
		MultiSynt	h used	0.0001	_	720	MHz
Duty Cycle	DC	f _{OUT} < 40	0 MHz	48	_	52	%
		400 MHz < f _{OUT}	< 1028 MHz	45	_	55	%
Output-Output Skew	T _{SKS}	Outputs on same MultiSynth		_	_	75	ps
Using Same MultiSynth		(Measured at 712.5 MHz)					
OUT-OUTb Skew	T _{SK_OUT}	Measured from the positive to negative output pins		_	0	50	ps
Output Voltage Swing ¹	V _{OUT}	LVD	S	350	430	510	mVpp_se
		LVPE	CL	640	750	900	-
Common Mode Voltage ¹	V _{CM}	V _{DDO} = 3.3 V	LVDS	1.10	1.2	1.3	V
			LVPECL	1.90	2.0	2.1	1
		V _{DDO} = 2.5 V	LVPECL	1.1	1.2	1.3	
			LVDS				
		V _{DDO} = 1.8 V	Sub-LVDS	0.8	0.9	1.0	
Rise and Fall Times	t _R /t _F			_	100	150	ps
(20% to 80%)							
Differential Output Impedance	Z _O			_	100	_	Ω
Power Supply Noise Rejection ²	PSRR	10 kHz sinus	oidal noise	_	-101	_	dBc
		100 kHz sinusoidal noise		_	-96	_	1
		500 kHz sinus	oidal noise	_	-99	-	1
		1 MHz sinuso	oidal noise	_	-97	_	1
Output-Output Crosstalk ³	XTALK	Si539	91	_	-72	_	dBc

Notes:

 Output amplitude and common-mode settings are programmable through register settings and can be stored in NVM. Each output driver can be programmed independently. The maximum LVDS single-ended amplitude can be up to 110 mV higher than the TIA/EIA-644 maximum. Refer to the Si5391 Family Reference Manual for more suggested output settings. Not all combinations of voltage amplitude and common mode voltages settings are possible.



- 2. Measured for 156.25 MHz carrier frequency. 100 mVpp sinewave noise added to VDDO = 3.3 V and noise spur amplitude measured.
- 3. Measured across two adjacent outputs, both in LVDS mode, with the victim running at 155.52 MHz and the aggressor at 156.25 MHz.

Table 6.6. LVCMOS Clock Output Specifications

(V_{DD} =1.8 V \pm 5%, V_{DDA}= 3.3 V \pm 5%, V_{DDO}= 1.8 V \pm 5%, 2.5 V \pm 5%, or 3.3 V \pm 5%, T_A = -40 to 85 °C)

Parameter	Symbol	Test Condit	ion	Min	Тур	Мах	Units
Output Frequency				0.0001	_	250	MHz
Duty Cycle	DC	f _{OUT} < 100 M	lHz	48	—	52	%
		100 MHz < f _{OUT} <	100 MHz < f _{OUT} < 250 MHz		_	55	
Output Voltage High ^{1, 2, 3}	V _{OH}	V _{DDO} = 3.3 V					
		OUTx_CMOS_DRV=1	I _{OH =} -10 mA	V _{DDO} x 0.85	_	_	V
		OUTx_CMOS_DRV=2	I _{OH =} -12 mA		_	_	
		OUTx_CMOS_DRV=3	I _{OH =} -17 mA		_	_	
		V _{DDO} = 2.5 V					
		OUTx_CMOS_DRV=1	I _{OH =} -6 mA	V _{DDO} x 0.85	_	_	V
		OUTx_CMOS_DRV=2	I _{OH =} -8 mA		_	_	
		OUTx_CMOS_DRV=3	I _{OH =} -11 mA		_	_	
		V _{DDO} = 1.8 V		11			
		OUTx_CMOS_DRV=2	I _{OH =} -4 mA	V _{DDO} x 0.85	_		V
		OUTx_CMOS_DRV=3	I _{OH =} -5 mA	-	_	_	
Output Voltage Low ^{1, 2, 3}	V _{OL}	V _{DDO} = 3.3 V					
		OUTx_CMOS_DRV=1	I _{OL} = 10 mA	_	_	V _{DDO} x 0.15 V	V
		OUTx_CMOS_DRV=2	I _{OL} = 12 mA	_			
		OUTx_CMOS_DRV=3	I _{OL} = 17 mA	_	_		
		V _{DDO} = 2.5 V		11			
		OUTx_CMOS_DRV=1	I _{OL} = 6 mA	_	_	V _{DDO} x 0.15	V
		OUTx_CMOS_DRV=2	I _{OL} = 8 mA	_	_	-	
		OUTx_CMOS_DRV=3	I _{OL} = 11 mA	_	_	_	
		V _{DDO} = 1.8 V					
		OUTx_CMOS_DRV=2	I _{OL} = 4 mA	_	_	V _{DDO} x 0.15	V
		OUTx_CMOS_DRV=3	I _{OL} = 5 mA	_	_		
LVCMOS Rise and Fall	tr/tf	VDDO = 3.3	3V		400	600	ps
Times ³		VDDO = 2.5	V		450	600	ps
(20% to 80%)		VDDO = 1.8	V		550	750	ps

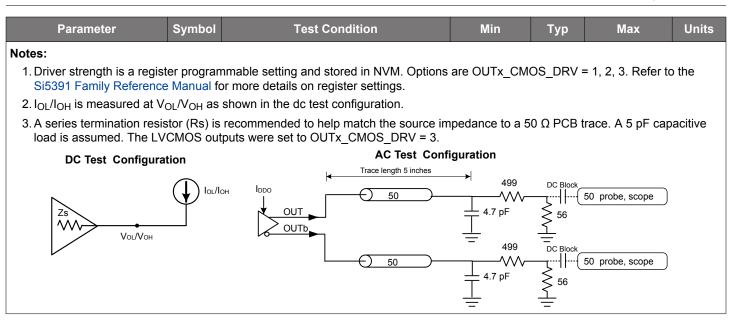


Table 6.7. Output Status Pin Specifications

$(V_{DD} = 1.8 \text{ V} \pm 5\%, V_{DDA} = 3.3 \text{ V} \pm 5\%, V_{DDS} = 3.3 \text{ V} \pm 5\%, 1.8 \text{ V} \pm 5\%, T_A = -40 \text{ to } 85^{\circ}\text{C})$

Parameter	Symbol	Test Condition	Min	Тур	Max	Units
Si5391 Status Output Pins (IN	(Rb, SDA/SDIO) ¹					
Output Voltage	V _{OH}	I _{OH} = -2 mA	V _{DDIO} ² x 0.85	—	_	V
	V _{OL}	I _{OL} = 2 mA	_	—	V _{DDIO} ² x 0.15	V
Si5391 Status Output Pins (LO	Lb)					
Output Voltage	V _{OH}	I _{OH} = -2 mA	V _{DDIO} ² x 0.85	—	-	V
	V _{OL}	I _{OL} = 2 mA	_	_	V _{DDIO} ² x 0.15	V

Notes:

1. The V_{OH} specification does not apply to the open-drain SDA/SDIO output when the serial interface is in I2C mode or is unused with I2C_SEL pulled high. V_{OL} remains valid in all cases.

2. V_{DDIO} is determined by the IO_VDD_SEL bit. It is selectable as V_{DDA} or V_{DD}. Refer to the Si5391 Family Reference Manual for more details on register settings.

Table 6.8. Performance Characteristics

(V_{DD}= 1.8 V ± 5%, V_{DDA}= 3.3 V ± 5%, T_A= –40 to 85 °C)

Parameter	Symbol	Test Condition		Min	Тур	Max	Units
PLL Loop Bandwidth	f _{BW}			_	1.0	—	MHz
Initial Start-Up Time	t _{START}	Time from power-up to erates clocks (Input F	o when the device gen- requency >48 MHz)	_	30	45	ms
PLL Lock Time ¹	t _{ACQ}	f _{IN} = 19.44 MHz		15	_	150	ms
POR ² to Serial Interface Ready	t _{RDY}			—		15	ms
RMS Phase Jitter ⁵ (Grade	J_{GEN} = 48 MHz crystal		f _{OUT} = 156.25 MHz		69	90	fs
P)		_	f _{OUT} = 312.5 MHz		69	95	fs
			f _{OUT} = 100 MHz		150	200	fs
			f _{OUT} = 50/25 MHz		200	300	fs
RMS Phase Jitter ⁶ (Grade A/B/C/D)	J_{GEN}	f _{IN} = 48 MHz crystal	Output divider Integer Mode ₃		75	115	fs
			Output divider Frac- tional Mode ⁴		115	145	fs
RMS Phase Jitter ⁶ (Grade A/B/C/D)	er ⁶ (Grade J _{GEN} f _{IN} = 100 MHz clock		Output divider Integer Mode ₃		145	195	fs
			Output divider Frac- tional Mode ⁴		165	215	fs

Parameter	Symbol	Test Condition	Min	Тур	Max	Units
Notes:						
	,	tting the PLL lock, then turning off the input cloc clock being re-applied until LOL de-asserts is th	,	0	the input clo	ock. The
		d V _{DD33} rails (90% of their value) to when the s le, with SCLK @ 10 MHz.	erial interfa	ce is ready t	to respond t	o com-
3. Integer mode assume	s that the outp	ut dividers (Nn/Nd) are configured with an integ	jer value.			
4. Fractional and DCO r er is integer.	nodes assume	that the output dividers (Nn/Nd) are configured	with a fract	ional value a	and the feed	back divi
	to be LVPECL	erformance in 56G/112G SerDes applications a , and an unused output is required between the Grade P				

6. Grade A/B/C/D are targeted for applications that require more flexibility and set the output divider to Integer or Fractional modes. Integer mode test conditions: fin = 100MHz, fout = 156.25MHz (MultiSynth in integer mode). Fractional mode test conditions: fin = 100MHz, fout = 156.25MHz (Multisynth in fractional mode). Outputs are assumed to be LVPECL. For more details, refer to 4.5.1 Grade A/B/C/D.

Parameter	Symbol Test Condition			Standard Mode 100 kbps		Fast Mode 400 kbps	
			Min	Мах	Min	Мах	
SCL Clock Frequency	f _{SCL}		—	100	—	400	kHz
Hold Time (Repeated) START Condition	t _{HD:STA}		4.0	_	0.6	-	μs
Low Period of the SCL Clock	t _{LOW}		4.7	_	1.3	_	μs
HIGH Period of the SCL Clock	thigh		4.0	_	0.6	-	μs
Set-up Time for a Repeated START Condition	t _{SU:STA}		4.7	_	0.6	_	μs
Data Hold Time	t _{HD:DAT}		100	_	100	_	ns
Data Set-up Time	t _{SU:DAT}		250	_	100	_	ns
Rise Time of Both SDA and SCL Signals	t _r			1000	20	300	ns
Fall Time of Both SDA and SCL Signals	t _f		_	300	_	300	ns
Set-up Time for STOP Con- dition	tsu:sto		4.0	_	0.6	_	μs
Bus Free Time between a STOP and START Condition	t _{BUF}		4.7	_	1.3	_	μs
Data Valid Time	t _{VD:DAT}		_	3.45	_	0.9	μs
Data Valid Acknowledge Time	t _{VD:ACK}		_	3.45	—	0.9	μs

Table 6.9. I²C Timing Specifications (SCL,SDA)

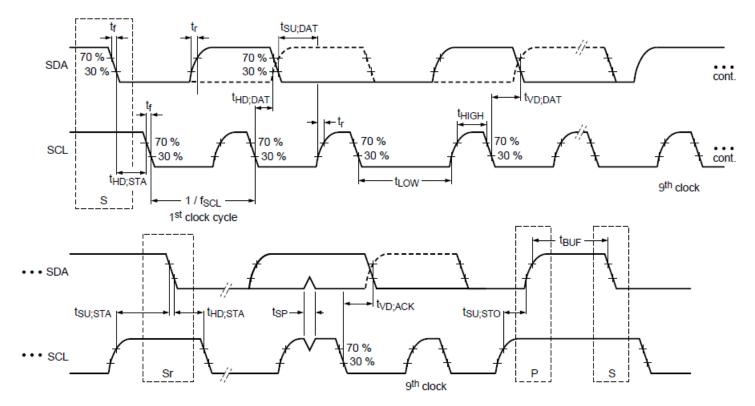


Figure 6.1. I²C Serial Port Timing Standard and Fast Modes

Table 6.10. SPI Timing Specifications (4-Wire)

(V_{DD}=1.8 V ± 5%, V_{DDA}=3.3 V ± 5%, T_A= -40 to 85 °C)

Parameter	Symbol	Min	Тур	Мах	Units
SCLK Frequency	f _{SPI}	_	_	20	MHz
SCLK Duty Cycle	T _{DC}	40	_	60	%
SCLK Period	T _C	50	_	_	ns
Delay Time, SCLK Fall to SDO Active	T _{D1}	_	_	18	ns
Delay Time, SCLK Fall to SDO	T _{D2}	_	_	15	ns
Delay Time, CSb Rise to SDO Tri-State	T _{D3}	_	_	15	ns
Setup Time, CSb to SCLK	T _{SU1}	5	_		ns
Hold Time, CSb to SCLK Rise	T _{H1}	5	_	_	ns
Setup Time, SDI to SCLK Rise	T _{SU2}	5	_	_	ns
Hold Time, SDI to SCLK Rise	T _{H2}	5	_	_	ns
Delay Time Between Chip Selects (CSb)	T _{CS}	2	_		Т _С

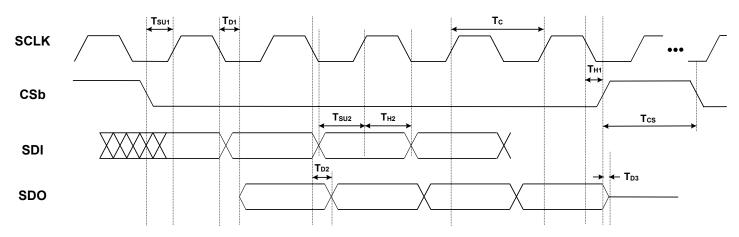


Figure 6.2. 4-Wire SPI Serial Interface Timing

Table 6.11. SPI Timing Specifications (3-Wire)

(V_{DD}=1.8 V ± 5%, V_{DDA}= 3.3 V ± 5%, T_A= –40 to 85 °C)

Parameter	Symbol	Min	Тур	Мах	Units
SCLK Frequency	f _{SPI}	—	_	20	MHz
SCLK Duty Cycle	T _{DC}	40	_	60	%
SCLK Period	T _C	50	_	_	ns
Delay Time, SCLK Fall to SDO Turn-on	T _{D1}	_	_	20	ns
Delay Time, SCLK Fall to SDO Next-bit	T _{D2}	_	_	15	ns
Delay Time, CSb Rise to SDO Tri-State	T _{D3}	_	_	15	ns
Setup Time, CSb to SCLK	T _{SU1}	5	_		ns
Hold Time, CSb to SCLK Rise	T _{H1}	5	_	_	ns
Setup Time, SDI to SCLK Rise	T _{SU2}	5	_	_	ns
Hold Time, SDI to SCLK Rise	T _{H2}	5	_	_	ns
Delay Time Between Chip Selects (CSb)	T _{CS}	2	—	_	T _C

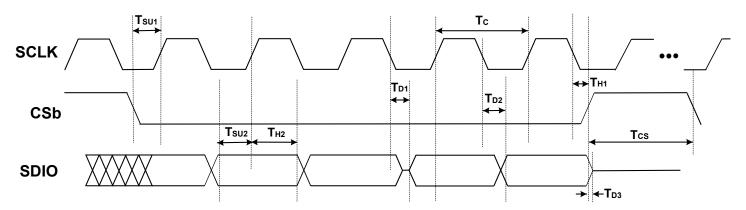


Figure 6.3. 3-Wire SPI Serial Interface Timing

Table 6.12. Crystal Specifications

Parameter	Symbol	Test Condition	Min	Тур	Мах	Units
Crystal Frequency Range Si5391P requires 48 MHz	f _{XTAL}	Full operating range. Jitter per- formance may be reduced.	24.97	_	54.06	MHz
XTAL		Range for best jitter.	48		54	MHz
Load Capacitance	CL		_	8	_	pF
Crystal Drive Level	dL				200	μW
Equivalent Series Resistance	r _{ESR}	Refer to the Si5391 Family Refer tance.	ence Manual	to determine	ESR and shu	nt capaci-
Shunt Capacitance	Co					

Note:

1. Refer to the Si534x/8x Recommended Crystal, TCXO and OCXOs Reference Manual for recommended 48 to 54 MHz crystals. The Si5391 is designed to work with crystals that meet these specifications.

Table 6.13. Thermal Characteristics

Parameter	Symbol	Test Condition ¹	Value	Units
Si5391 - 64QFN				
Thermal Resistance	θ _{JA}	Still Air	22	°C/W
Junction to Ambient		Air Flow 1 m/s	19.4	
		Air Flow 2 m/s	18.3	
Thermal Resistance	θ _{JC}		9.5	
Junction to Case				
Thermal Resistance	θ _{JB}		9.4	
Junction to Board	Ψ _{JB}		9.3	
Thermal Resistance	Ψ _{JT}		0.2	
Junction to Top Center				

1. Based on PCB Dimension: 3 x 4.5 mm, PCB Land/Via under GND pad: 36, Number of Cu Layers: 4

Parameter	Symbol	Test Condition	Value	Units
Storage Temperature Range	T _{STG}		-55 to +150	°C
DC Supply Voltage	V _{DD}		-0.5 to 3.8	V
	V _{DDA}		-0.5 to 3.8	V
	V _{DDO}		-0.5 to 3.8	V
Input Voltage Range	V _{I1}	IN0-IN2, FB_IN	-1.0 to 3.8	V
	V _{I2}	IN_SEL[1:0], RSTb, OEb, SYNCb, I2C_SEL, SDI, SCLK, A0/CSb, A1, SDA/SDIO, FINC/ FDEC	-0.5 to 3.8	V
	V _{I3}	XA/XB	-0.5 to 2.7	V
Latch-up Tolerance	LU		JESD78 (Compliant
ESD Tolerance	НВМ	100 pF, 1.5 kΩ	2.0	kV
Maximum Junction Temperature in Operation	T _{JCT}		125	°C
Soldering Temperature (Pb-free profile) ³	T _{PEAK}		260	°C
Soldering Temperature Time at T _{PEAK}	Τ _Ρ		20 to 40	sec
(Pb-free profile) ³				

Table 6.14. Absolute Maximum Ratings^{1, 2, 3}

Notes:

1. Permanent device damage may occur if the absolute maximum ratings are exceeded. Functional operation should be restricted to the conditions as specified in the operational sections of this data sheet. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

2.64-QFN packages are RoHS-6 compliant.

3. The device is compliant with JEDEC J-STD-020.

7. Detailed Block Diagrams

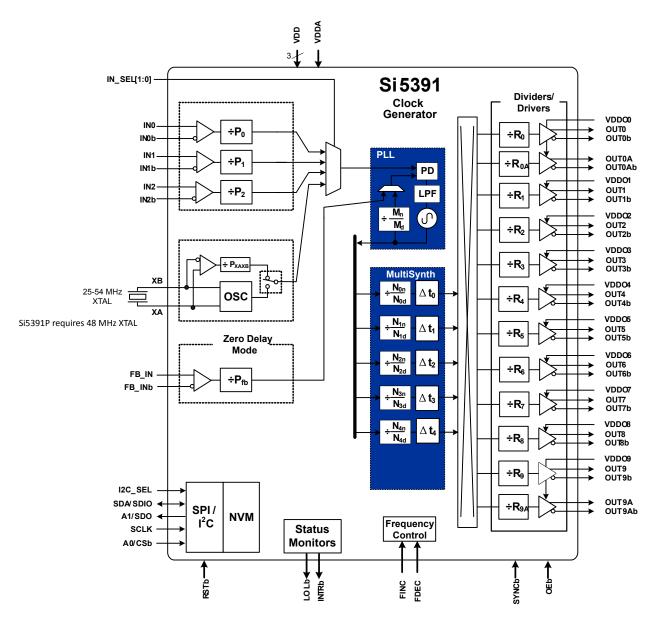


Figure 7.1. Si5391 Block Diagram

8. Typical Operating Characteristics

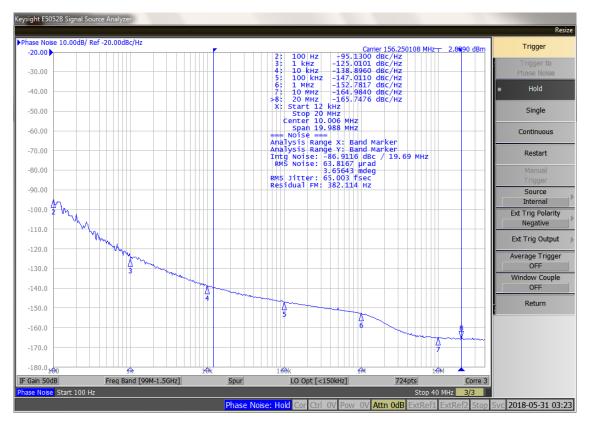
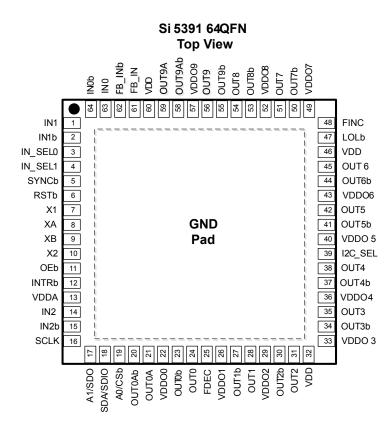


Figure 8.1. 156.25MHz Ouput (3.3V LVPECL) in Precision Calibration Mode (Grade P)

9. Pin Descriptions



Pin	Pin Number	Pin Type ¹	Function
Name	Si5391		
Inputs			
XA	8	I	Crystal and External Clock Input.
ХВ	9	Ι	These pins are used to connect an ex- ternal crystal or an external clock. See 4.3.1 XA/XB Clock and Crystal Input and Figure 4.2 XAXB External Crystal and Clock Connections on page 8 for connection information. If IN_SEL[1:0] = 11b, then the XAXB input is selec- ted. If the XAXB input is not used and powered down, then both inputs can be left unconnected. ClockBuilder Pro will power down an input that is set as "Unused".
X1	7	I	XTAL Shield. Connect these pins directly to the XTAL ground pins. X1,
X2	10	Ι	X2, and the XTAL ground pins. X1, X2, and the XTAL ground pins must not be connected to the PCB ground plane. DO NOT GROUND THE CRYSTAL GROUND PINS. Refer to the Si5391 Family Reference Manual for layout guidelines. These pins should be left disconnected when con- necting XA/XB pins to an external ref- erence clock.
IN0	63	Ι	Clock Inputs. These pins accept both differential and single-ended clock sig-
IN0b	64	Ι	nals. Refer 4.3.2 Input Clocks (IN0,
IN1	1	I	IN1, IN2) for input termination options. These pins are high-impedance and
IN1b	2	I	must be terminated externally. If both the INx and INxb inputs are un-used
IN2	14	I	and powered down, then both inputs
IN2b	15	I	can be left floating. ClockBuilder Pro will power down an input that is set as "Unused".
FB_IN	61	I	External Feedback Input. These pins are used as the external feedback in-
FB_INb	62	I	are used as the external feedback in- put (FB_IN/FB_INb) for the optional zero delay mode. See 4.5.13 Zero De- lay Mode (Grade A/B/C/D) for details on the optional zero delay mode. If FB_IN and FB_INb are un-used and powered down, then both inputs can be left floating. ClockBuilder Pro will power down an input that is set as "Unused".

Table 9.1. Pin Descriptions

Pin Name	Pin Number	Pin Type ¹	Function
	Si5391		
Outputs			1
OUT0	24	0	Output Clocks. These output clocks support a programmable signal amplitude when configured as a differential output. Desired
OUT0b	23	0	output signal format is configurable using register control. Termi- nation recommendations are provided in 4.5.4 Differential Output
OUT0A	21	0	Terminations and 4.5.6 LVCMOS Output Terminations. Unused
OUT0Ab	20	0	outputs should be left unconnected.
OUT1	28	0	_
OUT1b	27	0	_
OUT2	31	0	_
OUT2b	30	0	_
OUT3	35	0	_
OUT3b	34	0	_
OUT4	38	0	_
OUT4b	37	0	_
OUT5	42	0	
OUT5b	41	0	
OUT6	45	0	
OUT6b	44	0	
OUT7	51	0	
OUT7b	50	0	
OUT8	54	0	
OUT8b	53	0	
OUT9	56	0	
OUT9b	55	0	
OUT9A	59	0	
OUT9Ab	58	0	
Serial Interface	•		
I2C_SEL	39	I	I ² C Select. ² This pin selects the serial interface mode as I ² C (I2C_SEL = 1) or SPI (I2C_SEL = 0). This pin is internally pulled up by a ~ 20 kΩ resistor to the voltage selected by the IO_VDD_SEL register bit.
SDA/SDIO	18	I/O	Serial Data Interface. ² This is the bidirectional data pin (SDA) for the I ² C mode, or the bidirectional data pin (SDIO) in the 3-wire SPI mode, or the input data pin (SDI) in 4-wire SPI mode. When in I ² C mode, this pin must be pulled-up using an external resistor of at least 1 k Ω . No pull-up resistor is needed when in SPI mode.
A1/SDO	17	I/O	Address Select 1/Serial Data Output. ² In I ² C mode, this pin functions as the A1 address input pin and does not have an internal pull up or pull down resistor. In 4-wire SPI mode this is the serial data output (SDO) pin (SDO) pin and drives high to the voltage selected by the IO_VDD_SEL pin.

Pin Name	Pin Number Si5391	Pin Type ¹	Function
SCLK	16	I	Serial Clock Input. ² This pin functions as the serial clock input for both I ² C and SPI modes. This pin is internally pulled up by a ~20 k Ω resistor to the voltage selected by the IO_VDD_SEL register bit. In I ² C mode this pin should have an external pull up of at least 1 k Ω . No pull-up resistor is needed when in SPI mode.
A0/CSb	19	1	Address Select 0/Chip Select. ² This pin functions as the hard- ware controlled address A0 in I ² C mode. In SPI mode, this pin functions as the chip select input (active low). This pin is internally pulled up by a ~20 k Ω resistor to the voltage selected by the IO_VDD_SEL register bit.
Control/Status			
INTRb	12	0	Interrupt. ² This pin is asserted low when a change in device status has occurred. This interrupt has a push pull output and should be left unconnected when not in use.
RSTb	6	I	Device Reset. ² Active low input that performs power-on reset (POR) of the device. Resets all internal logic to a known state and forces the device registers to their default values. Clock outputs are disabled during reset. This pin is internally pulled up with a ~20 k Ω resistor to the voltage selected by the IO_VDD_SEL bit.
OEb	11	I	Output Enable. ² This pin disables all outputs when held high. This pin is internally pulled low and can be left unconnected when not in use.
LOLb	47	0	Loss Of Lock. ² This output pin indicates when the DSPLL [™] is locked (high) or out-of-lock (low). An external pull up or pull down is not needed.
SYNCb	5	I	Output Clock Synchronization. ² An active low signal on this pin resets the output dividers for the purpose of re-aligning the output clocks. For a tighter alignment of the clocks, a soft reset should be applied. This pin is internally pulled up with a ~20 k Ω resistor to the voltage selected by the IO_VDD_SEL bit and can be left unconnected when not in use.
FDEC	25	I	Frequency Decrement Pin. ² This pin is used to step-down the output frequency of a selected output. The affected output driver and its frequency change step size is register configurable. This pin is internally pulled low with a ~20 k Ω resistor and can be left unconnected when not in use.
FINC	48	I	Frequency Increment Pin. ² This pin is used to step-up the output frequency of a selected output. The affected output and its frequency change step size is register configurable. This pin is internally pulled low with a ~20 k Ω resistor and can be left unconnected when not in use.
IN_SEL0	3	I	Input Reference Select. ² The IN_SEL[1:0] pins are used in the
IN_SEL1	4	I	manual pin controlled mode to select the active clock input. These pins are internally pulled up with a ~20 k Ω resistor to the voltage selected by the IO_VDD_SEL bit and can be left unconnected when not in use.
Power	•		
VDD	32	Р	Core Supply Voltage. The device core operates from a 1.8 V
	46		supply. A 1.0 µf bypass capacitor is recommended.
	60		
L	I		

Pin Name	Pin Number Si5391	Pin Type ¹	Function
VDDA	13	P	Core Supply Voltage 3.3 V. This core supply pin requires a 3.3 power source. A 1.0 μf bypass capacitor is recommended.
VDDO0	22	Р	Output Clock Supply Voltage 0-9. Supply voltage (3.3 V, 2.5 V
VDDO1	26	Р	 1.8 V) for OUTx, OUTx outputs. See the Si5391 Family Reference Manual for power supply filtering recommendations. Leave VDD0
VDDO2	29	Р	pins of unused output drivers unconnected. An alternate option is to connect the VDDO pin to a power supply and disable the outp
VDDO3	33	Р	driver to minimize current consumption.
VDDO4	36	Р	
VDDO5	40	Р	
VDDO6	43	Р	-
VDD07	49	Р	
VDDO8	52	Р	-
VDDO9	57	Р	-
GND PAD		Ρ	Ground Pad This pad provides electrical and thermal connection to ground and must be connected for proper operation. Use as many vias as practical and keep the via length to an internal ground plan as short as possible.
lote:		1	1

2. The IO_VDD_SEL control bit (0x0943 bit 0) selects 3.3 V or 1.8 V operation.

10. Package Outlines

10.1 Si5391 9x9 mm 64-QFN Package Diagram

The figure below illustrates the package details for the Si5391. The table below lists the values for the dimensions shown in the illustration.

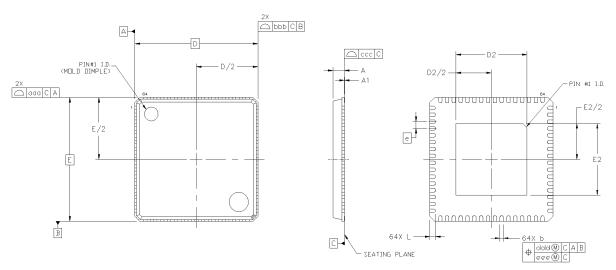


Figure 10.1. 64-Pin Quad Flat No-Lead (QFN)

Table 10.1.	Package Dimensions
-------------	--------------------

Dimension	Min	Nom	Мах
A	0.80	0.85	0.90
A1	0.00	0.02	0.05
b	0.18	0.25	0.30
D		9.00 BSC	
D2	5.10	5.20	5.30
e		0.50 BSC	
E	9.00 BSC		
E2	5.10	5.20	5.30
L	0.30	0.40	0.50
ааа	—	—	0.15
bbb	_	_	0.10
ссс	_	—	0.08
ddd	—	—	0.10
eee	—	—	0.05

Notes:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

3. This drawing conforms to the JEDEC Solid State Outline MO-220.

4. Recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

11. PCB Land Pattern

The figure below illustrates the PCB land pattern details for the devices. The table below lists the values for the dimensions shown in the illustration.

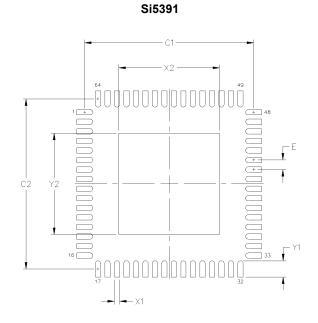


Figure 11.1. PCB Land Pattern

Table 11.1. PCB Land Pattern Dimensions

Dimension	Si5391 (Max)
C1	8.90
C2	8.90
E	0.50
X1	0.30
Y1	0.85
X2	5.30
Y2	5.30

Notes:

General

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. This Land Pattern Design is based on the IPC-7351 guidelines.
- 3. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition is calculated based on a fabrication Allowance of 0.05 mm.

Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

Stencil Design

- 1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
- 2. The stencil thickness should be 0.125 mm (5 mils).
- 3. The ratio of stencil aperture to land pad size should be 1:1 for all perimeter pads.
- 4. A 3×3 array of 1.25 mm square openings on 1.80 mm pitch should be used for the center ground pad.

Card Assembly

- 1. A No-Clean, Type-3 solder paste is recommended.
- 2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020 specification for Small Body Components.

12. Top Marking

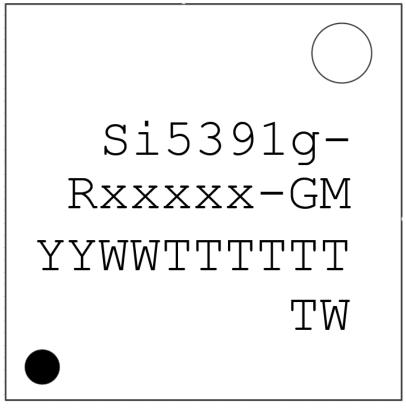


Figure 12.1. Si5391 Top Marking

Table 12.1.	Si5391	Тор	Marking	Explanation
-------------	--------	-----	---------	-------------

Line	Characters	Description
1	Si5391g-	Base part number and Device Grade for Low Jitter, Any-Frequency, 12-output Clock Generator.
		Si5391: 10-output, 64-QFN
		g = Device Grade (A, B, C, D, P). See 3. Ordering Guide for more information.
		– = Dash character.
2	Rxxxx-GM	R = Product revision. (See ordering guide for current revision).
		xxxxx = Customer specific NVM sequence number. Optional NVM code assigned for custom, factory pre-programmed devices.
		Characters are not included for standard, factory default configured devices. See Or- dering Guide for more information.
		–GM = Package (QFN) and temperature range (–40 to +85 °C)
3	YYWWTTTTTT	YYWW = Characters correspond to the year (YY) and work week (WW) of package assembly.
		TTTTTT = Manufacturing trace code.
4	Circle w/ 1.6 mm (64-QFN) diam- eter	Pin 1 indicator; left-justified
	TW	TW = Taiwan; Country of Origin (ISO Abbreviation)

13. Device Errata

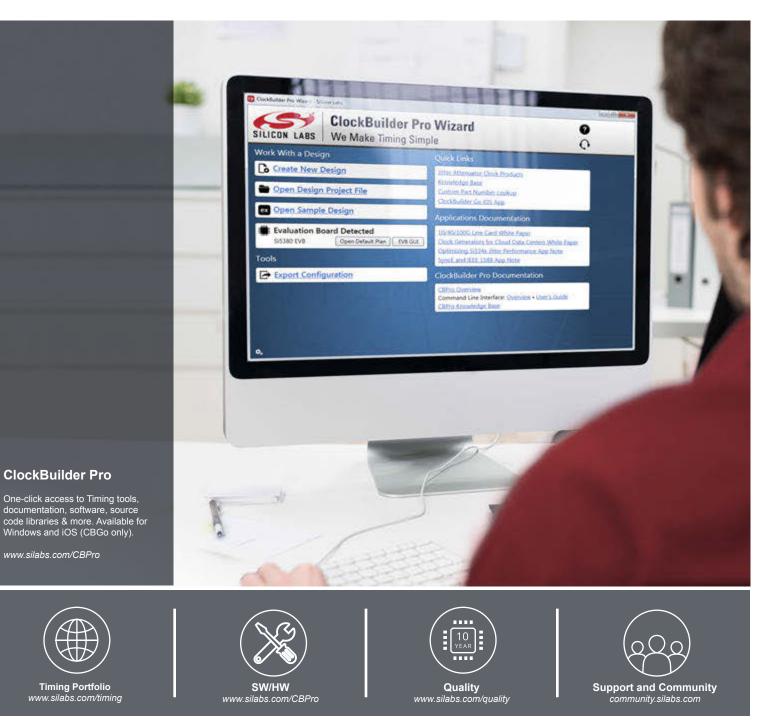
Please log in or register at www.silabs.com to access the device errata document.

14. Revision History

Revision 0.7

June 2018

· Initial release.



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